

PDTA143X/123J/143Z/114Y/124XQB

Series

50 V, 100 mA PNP resistor-equipped transistors

Rev. 1 — 28 September 2021 Pro

Product data sheet

1. General description

100 mA PNP Resistor-Equipped Transistor (RET) family in an ultra small DFN1110D-3 (SOT8015) leadless Surface-Mounted Device (SMD) plastic package with side-wettable flanks.

Table 1. Product overview

Type number	R1	R2		Package	NPN complement:
	kΩ	kΩ	Nexperia	JEDEC	
PDTA143XQB	4.7	10	SOT8015	MO-340BA	PDTC143XQB
PDTA123JQB	2.2	47			PDTC123JQB
PDTA143ZQB	4.7	47			PDTC143ZQB
PDTA114YQB	10	47			PDTC114YQB
PDTA124XQB	22	47			PDTC124XQB

2. Features and benefits

- 100 mA output current capability
- **Built-in resistors**
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- Low package height of 0.5 mm
- Suitable for Automatic Optical Inspection (AOI) of solder joint

3. Applications

- Digital applications
- Cost saving alternative for BC857 series in digital applications
- Controlling IC inputs
- Switching loads

4. Quick reference data

Table 2. Quick reference data

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	-50	V
Io	output current		-	-	-100	mA



5. Pinning information

Table 3. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	I	input (base)		
2	GND	GND (emitter)	3	R1
3	0	output (collector)		GND R2
			Transparent top view	aaa-019606

6. Ordering information

Table 4. Ordering information

Type number	Package					
	Name	Description	Version			
PDTA143XQB	DFN1110D-3	plastic leadless extremely thin small outline package with	SOT8015			
PDTA123JQB		side-wettable flanks (SWF); 3 terminals; 0.65 mm pitch; body: 1.1 x 1.0 x 0.48 mm				
PDTA143ZQB		body. 1.1 x 1.0 x 0.40 mm				
PDTA114YQB						
PDTA124XQB	7					

7. Marking

Table 5. Marking

Type number	Marking code
PDTA143XQB	D6
PDTA123JQB	D2
PDTA143ZQB	D7
PDTA114YQB	C9
PDTA124XQB	D4

8. Limiting values

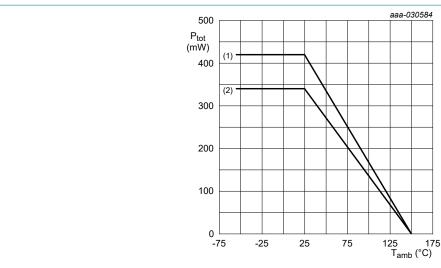
Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Max	Unit			
V _{CBO}	collector-base voltage	open emitter		-	-50	V			
V _{CEO}	collector-emitter voltage	open base		-	-50	V			
V _{EBO}	emitter-base voltage		,						
	PDTA143XQB	open collector		-	-7	V			
	PDTA123JQB			-	-5	V			
	PDTA143ZQB			-	-5	V			
	PDTA114YQB			-	-6	V			
	PDTA124XQB			-	-7	V			
VI	input voltage								
	PDTA143XQB			-30	+7	V			
	PDTA123JQB			-12	+5	V			
	PDTA143ZQB			-30	+5	V			
	PDTA114YQB			-40	+6	V			
	PDTA124XQB			-40	+7	V			
Io	output current			-	-100	mA			
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	340	mW			
			[2]	-	420	mW			
T _j	junction temperature			-	150	°C			
T _{amb}	ambient temperature			-55	150	°C			
T _{stg}	storage temperature			-65	150	°C			

- Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided; 35 µm copper; tin-plated and standard footprint.
- Device mounted on an FR4 PCB; single-sided; 70 µm copper; tin-plated and standard footprint.



(1) FR4 PCB; single-sided; 70 µm copper; standard footprint

(2) FR4 PCB; single-sided; 35 µm copper; standard footprint

Power derating curves Fig. 1.

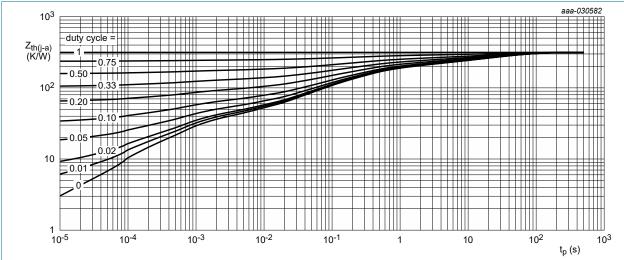
9. Thermal characteristics

Table 7. Thermal characteristics

 T_{amb} = 25 °C unless otherwise specified.

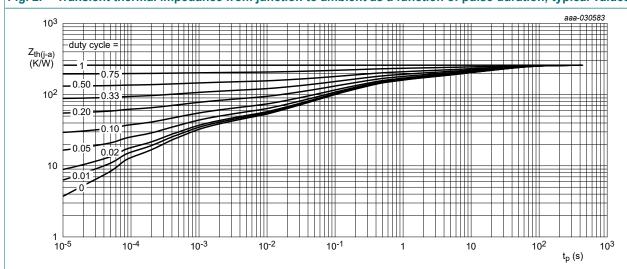
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	-	368	K/W
			[2]	-	-	298	K/W

- [1] Device mounted on an FR4 PCB; single-sided; 35 µm copper; tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB; single-sided; 70 μm copper; tin-plated and standard footprint.



FR4 PCB; single-sided; 35 µm copper; tin-plated and standard footprint.

Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB; single-sided; 70 µm copper; tin-plated and standard footprint.

Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

10. Characteristics

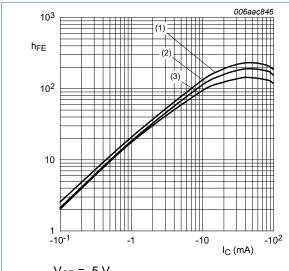
Table 8. Characteristics

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit			
V _{(BR)CBO}	collector-base breakdown voltage	I _C = -100 μA; I _E = 0 A	-50	-	-	V			
V _{(BR)CEO}	collector-emitter breakdown voltage	I _C = -2 mA; I _B = 0 A	-50	-	-	V			
I _{CBO}	collector-base cut-off current	$V_{CB} = -50 \text{ V}; I_E = 0 \text{ A}$	-	-	-100	nA			
I _{CEO}	collector-emitter cut-off	V _{CE} = -30 V; I _B = 0 A	-	-	-100	nA			
	current	V _{CE} = -30 V; I _B = 0 A; T _j = 150 °C	-	-	-5	μA			
I _{EBO}	emitter-base cut-off curr	ent		'					
	PDTA143XQB	V _{EB} = -5 V; I _C = 0 A	-	-	-600	μA			
	PDTA123JQB		-	-	-180	μA			
	PDTA143ZQB		-	-	-170	μA			
	PDTA114YQB				-150	μA			
	PDTA124XQB				-120	μA			
h _{FE}	DC current gain								
	PDTA143XQB	$V_{CE} = -5 \text{ V}; I_{C} = -10 \text{ mA}$	50	-	-	T			
	PDTA123JQB		100	-	-				
	PDTA143ZQB		100	-	-				
	PDTA114YQB	V _{CE} = -5 V; I _C = -5 mA	100	-	-				
	PDTA124XQB		80	-	-				
V _{CEsat}	collector-emitter saturation voltage								
	PDTA143XQB	I _C = -10 mA; I _B = -0.5 mA	-	-	-100	mV			
	PDTA123JQB	I _C = -5 mA; I _B = -0.25 mA	-	-	-100	mV			
	PDTA143ZQB		-	-	-100	mV			
	PDTA114YQB		-	-	-100	mV			
	PDTA124XQB	I _C = -10 mA; I _B = -0.5 mA	-	-	-100	mV			
V _{I(off)}	off-state input voltage								
	PDTA143XQB	V _{CE} = -5 V ; I _C = -100 μA	-	-0.9	-0.3	V			
	PDTA123JQB		-	-0.6	-0.5	V			
	PDTA143ZQB		-	-0.6	-0.5	V			
	PDTA114YQB	1	-	-0.7	-0.5	V			
	PDTA124XQB	1	-	-0.8	-0.5	V			
V _{I(on)}	on-state input voltage	1	1 1	1	1				
	PDTA143XQB	V _{CE} = -0.3 V ; I _C = -20 mA	-2.5	-1.5	-	V			
	PDTA123JQB	V _{CE} = -0.3 V ; I _C = -5 mA	-1.1	-0.75	-	V			
	PDTA143ZQB	V _{CE} = -0.3 V ; I _C = -5 mA	-1.3	-0.9	-	V			
	PDTA114YQB	V _{CE} = -0.3 V ; I _C = -1 mA	-1.4	-0.8	-	V			
	PDTA124XQB	V _{CE} = -0.3 V ; I _C = -2 mA	-2	-1.1	-	V			

Symbol	Parameter	Conditions		Min	Тур	Max	Unit			
R1	bias resistor 1 (input)	bias resistor 1 (input)								
	PDTA143XQB		[1]	3.3	4.7	6.1	kΩ			
	PDTA123JQB			1.54	2.2	2.86	kΩ			
	PDTA143ZQB			3.3	4.7	6.1	kΩ			
	PDTA114YQB			7	10	13	kΩ			
	PDTA124XQB			15.4	22	28.6	kΩ			
R2/R1	bias resistor ratio									
	PDTA143XQB		[1]	1.7	2.13	2.6				
	PDTA123JQB			17	21	26				
	PDTA143ZQB			8	10	12				
	PDTA114YQB			3.7	4.7	5.7				
	PDTA124XQB			1.7	2.13	2.6				
f _T	transition frequency	V _{CE} = -5 V; I _C = -10 mA; f = 100 MHz	[2]	-	180	-	MHz			
C _c	collector capacitance	V _{CB} = -10 V; I _E = i _e = 0 A; f = 1 MHz		-	-	3	pF			

- See "Section 11: Test information" for resistor calculation and test conditions
- Characteristics of built-in transistor



 $V_{CE} = -5 V$

(1) $T_{amb} = 100 \, ^{\circ}C$

(2) T_{amb} = 25 °C

(3) $T_{amb} = -40 \, ^{\circ}C$

PDTA143XQB: DC current gain as a function of Fig. 4. collector current; typical values

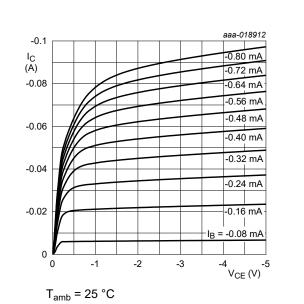
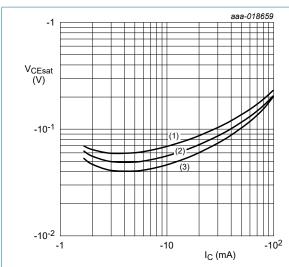


Fig. 5. PDTA143XQB: Collector current as a function of collector-emitter voltage; typical values



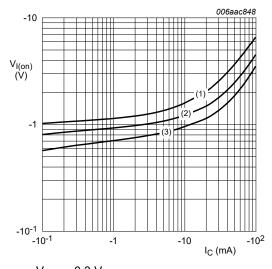
$$I_{\rm C}/I_{\rm B} = 20$$

(1)
$$T_{amb}$$
 = 100 °C

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -40 \, ^{\circ}C$$

PDTA143XQB: Collector-emitter saturation Fig. 6. voltage as a function of collector current; typical values



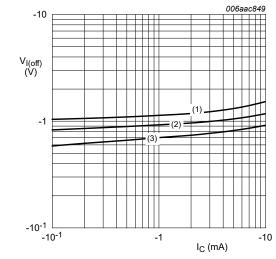
$$V_{CE}$$
 = -0.3 V

(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 7. PDTA143XQB: On-state input voltage as a function of collector current; typical values



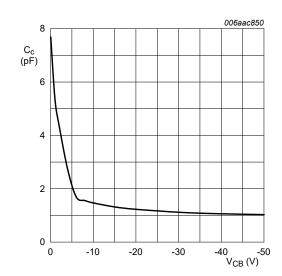
$$V_{CE} = -5 V$$

(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = 100 \, ^{\circ}C$$

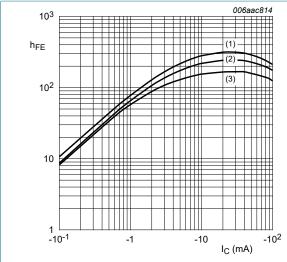
PDTA143XQB: Off-state input voltage as a Fig. 8. function of collector current; typical values



$$f = 1 MHz$$

PDTA143XQB: Collector capacitance as a Fig. 9. function of collector-base voltage; typical values

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$$V_{CE} = -5 V$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 10. PDTA123JQB: DC current gain as a function of collector current; typical values

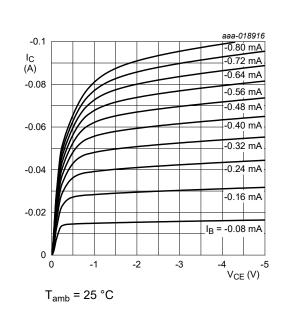
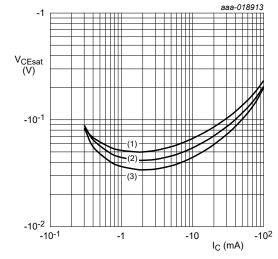


Fig. 11. PDTA123JQB: Collector current as a function of collector-emitter voltage; typical values



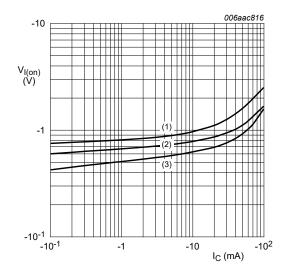
$$I_{\rm C}/I_{\rm B} = 20$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 12. PDTA123JQB: Collector-emitter saturation voltage as a function of collector current; typical values



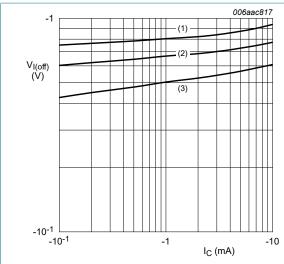
$$V_{CE} = -0.3 \text{ V}$$

(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 13. PDTA123JQB: On-state input voltage as a function of collector current; typical values



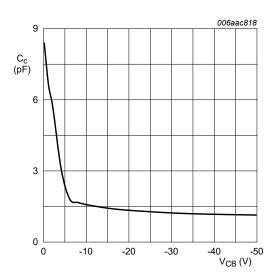
$$V_{CE} = -5 V$$

(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

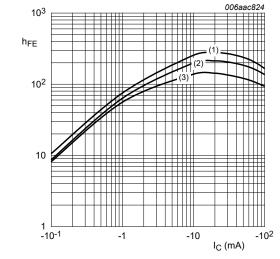
(3)
$$T_{amb}$$
 = 100 °C

Fig. 14. PDTA123JQB: Off-state input voltage as a function of collector current; typical values



$$T_{amb}$$
 = 25 °C

Fig. 15. PDTA123JQB: Collector capacitance as a function of collector-base voltage; typical values



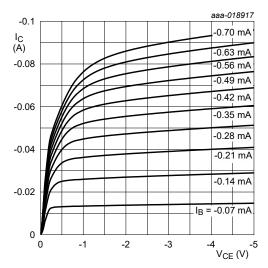
$$V_{CE} = -5 V$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

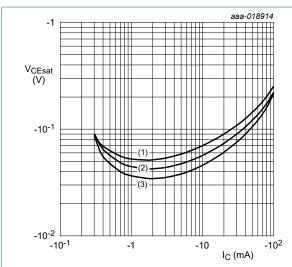
(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 16. PDTA143ZQB: DC current gain as a function of collector current; typical values



T_{amb} = 25 °C

Fig. 17. PDTA143ZQB: Collector current as a function of collector-emitter voltage; typical values



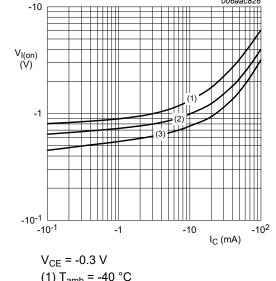
$$I_{\rm C}/I_{\rm B} = 20$$

(1)
$$T_{amb}$$
 = 100 °C

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 18. PDTA143ZQB: Collector-emitter saturation voltage as a function of collector current; typical values

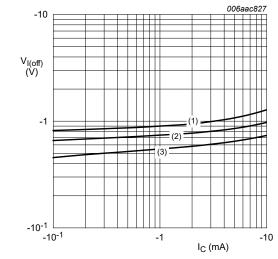


(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 19. PDTA143ZQB: On-state input voltage as a function of collector current; typical values



$$V_{CE} = -5 V$$

(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 20. PDTA143ZQB: Off-state input voltage as a function of collector current; typical values

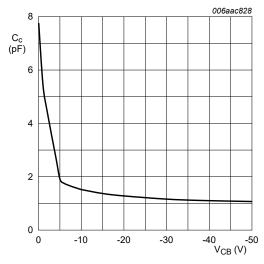
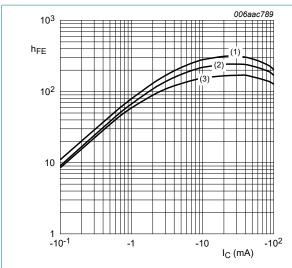


Fig. 21. PDTA143ZQB: Collector capacitance as a function of collector-base voltage; typical values



$$V_{CE} = -5 V$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 22. PDTA114YQB: DC current gain as a function of collector current; typical values

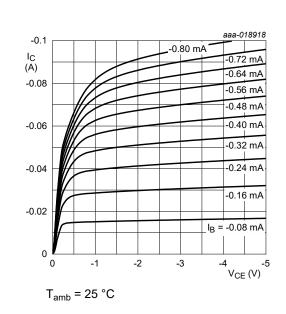
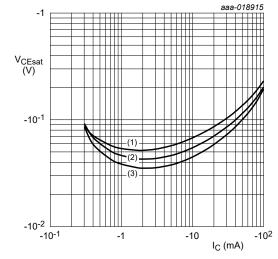


Fig. 23. PDTA114YQB: Collector current as a function of collector-emitter voltage; typical values



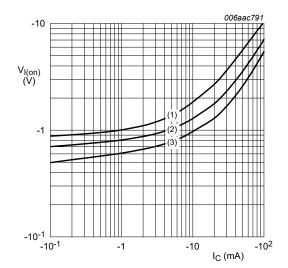
$$I_C/I_B = 20$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 24. PDTA114YQB: Collector-emitter saturation voltage as a function of collector current; typical values



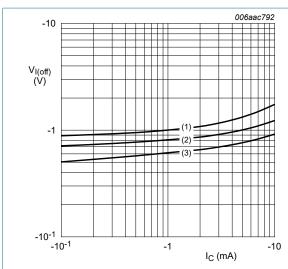
$$V_{CE} = -0.3 \text{ V}$$

(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 25. PDTA114YQB: On-state input voltage as a function of collector current; typical values

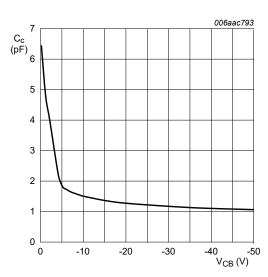


$$V_{CE} = -5 V$$

(1)
$$T_{amb}$$
 = -40 °C

(3)
$$T_{amb}$$
 = 100 °C

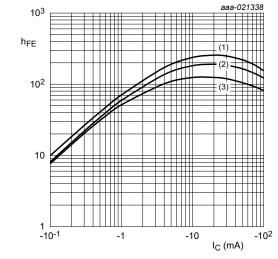
Fig. 26. PDTA114YQB: Off-state input voltage as a function of collector current; typical values



$$f = 1 MHz$$

$$T_{amb}$$
 = 25 °C

Fig. 27. PDTA114YQB: Collector capacitance as a function of collector-base voltage; typical values



 $V_{CE} = -5 V$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 28. PDTA124XQB: DC current gain as a function of collector current; typical values

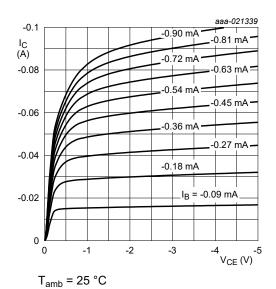
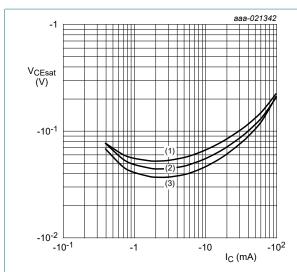


Fig. 29. PDTA124XQB: Collector current as a function of collector-emitter voltage; typical values



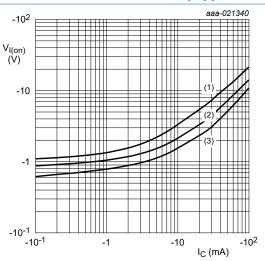
$$I_{\rm C}/I_{\rm B} = 10$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 30. PDTA124XQB: Collector-emitter saturation voltage as a function of collector current; typical values



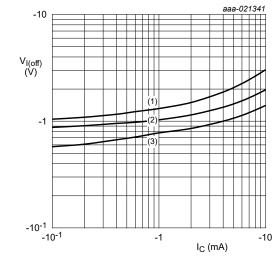
$$V_{CE} = -0.3 V$$

(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 31. PDTA124XQB: On-state input voltage as a function of collector current; typical values



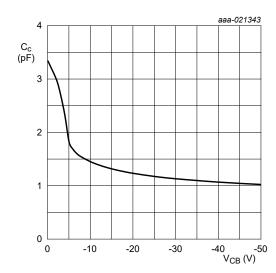
$$V_{CE} = -5 V$$

(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

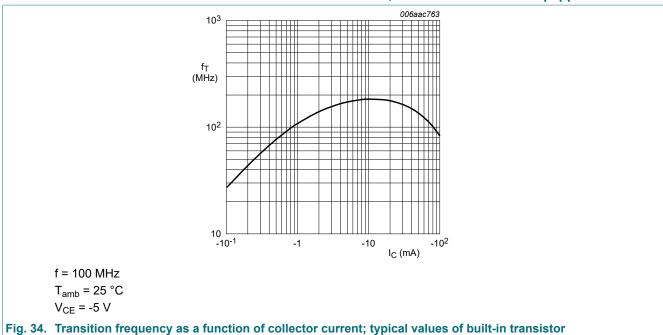
(3)
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 32. PDTA124XQB: Off-state input voltage as a function of collector current; typical values



f = 1 MHz

Fig. 33. PDTA124XQB: Collector capacitance as a function of collector-base voltage; typical values



11. Test information

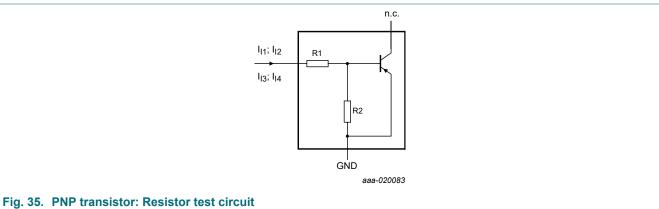
Resistor calculation

· Calculation of bias resistor 1 (R1)

$$R1 = \frac{V(I_{12}) - V(I_{11})}{I_{12} - I_{11}}$$

· Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I14) - V(I13)}{R1 \cdot (I14 - I13)} - 1$$

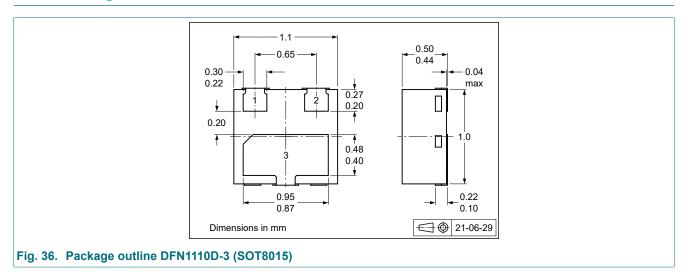


Resistor test conditions

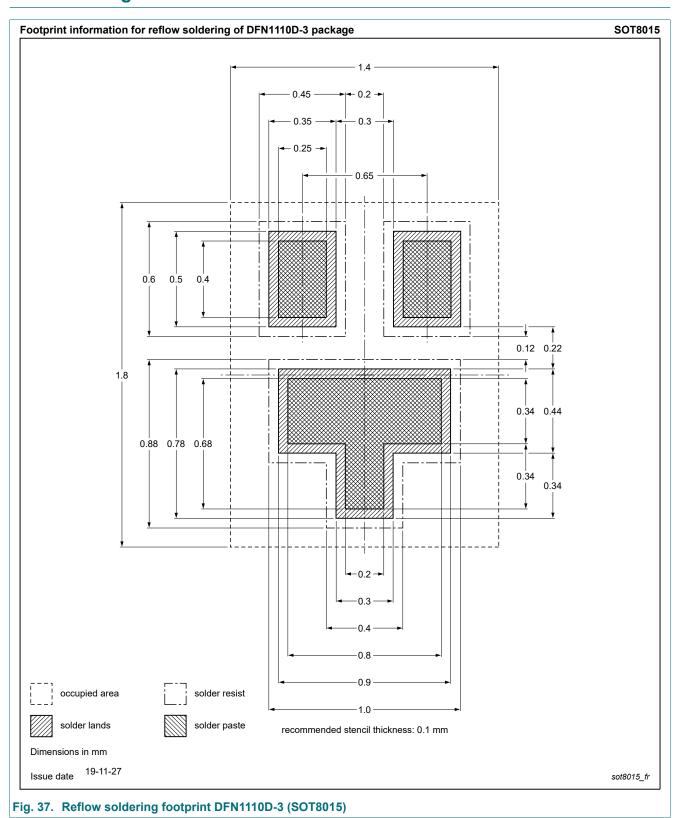
Table 9. Resistor test conditions

Type number	R1 (kΩ)	R2 (kΩ)	Test conditi	ons		
			I _{I1}	I _{I2}	I ₁₃	I _{I4}
PDTA143XQB	4.7	10	-350 μΑ	-450 μA	350 μΑ	450 µA
PDTA123JQB	2.2	47	-90 µA	-140 µA	55 μA	105 μΑ
PDTA143ZQB	4.7	47	-90 μA	-140 µA	55 µA	105 μΑ
PDTA114YQB	10	47	-90 μA	-140 µA	55 µA	105 μΑ
PDTA124XQB	22	47	-55 μΑ	-105 μA	55 μΑ	105 μΑ

12. Package outline



13. Soldering



14. Revision history

Table 10. Revision history

Data sheet ID	Release date		Change notice	Supersedes
PDTA143X_to_124XQB_SER v.1	20210928	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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50 V, 100 mA PNP resistor-equipped transistors

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